

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Agarwal et al.

Art Unit: 1765

Application No. --

Filed: Herewith

For: METHODS FOR FORMING AND
INTEGRATED CIRCUIT STRUCTURES
CONTAINING RUTHENIUM AND TUNGSTEN
CONTAINING LAYERS

Examiner: --

Date: October 29, 2001

COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

PRELIMINARY AMENDMENT

Before calculating the filing fee for the above-referenced divisional patent application, please amend the application as follows:

In the Specification:

Before page 1, line 4, please insert: -- This application is a divisional application of Application No. 09/590,795, filed June 8, 2000.--

In the Claims:

Please cancel claims 1-50 and 59-70 without prejudice.

REMARKS

Upon entry of this Preliminary Amendment, claims 51-58 and 71 are submitted for consideration in this divisional application of Application No. 09/590,795, filed June 6, 2000.

Respectfully submitted,

KLARQUIST SPARKMAN, LLP

By



Michael D. Jones
Registration No. 41,879

One World Trade Center, Suite 1600
121 S.W. Salmon Street
Portland, Oregon 97204
Telephone: (503) 226-7391
Facsimile: (503) 228-9446